# 2 cell Li-ion Battery Charge from 3V~12V

#### **General Description**

The LP28400A is a complete constant-current/ constant voltage switching charger for multi cell lithium-ion batteries. Boost + Linear charger work with a USB 2.0 compliant power IC assuring 2 cell Li-on battery charging. When the battery voltage is low, the charger works in linear operation mode. Along with the charging the battery voltage is higher the charger will transfer to Boost operation mode smoothly.

When the battery voltage <6V, switch to wake-up current charging.

Other features include charge current monitor, under voltage lockout, automatic recharge and a status pin to indicate charge termination.

L P Semi

### **Order Information**

LP28400A

F: Pb-Free

Package Type SP: ESOP8 QV: QFN-16

### **Applications**

- ♦ 2 cell Li-lon handheld devices
- ♦ POS device
- Bluetooth speaker
- USB powered devices

#### **Features**

- Adapter Adaptive
- Input voltage range 3V~12V
- Integrated low side power MOSFET
- Simple structure and perfect transition between
   Linear and Boost operation
- Programmable charge current and CV voltage
- Dynamic input current allocation for maximum charging rate
- Automatically switches to wake-up current when charging over-discharged batteries
- Over Current Protection
- Over Temperature Protection
- Consumption Available in ESOP8 & QFN16(3mm\*3mm) Package
- RoHS Compliant and 100% Lead (Pb)-Free
- Programmable Charge Mode for 2cells,3cells or 4cells charging (QFN-16 package only)

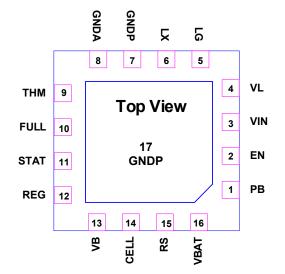
### **Marking Information**

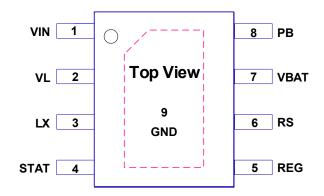
Device	Marking	Package	Shipping		
LP28400ASPF	LPS	ESOP8	4K/REEL		
LP28400AQVF	LP28400A YWX	QFN-16	5K/REEL		
Marking indication:					
Y:Production year W:Production week X:Series Number					

**Preliminary** 

# **Functional Pin Description**

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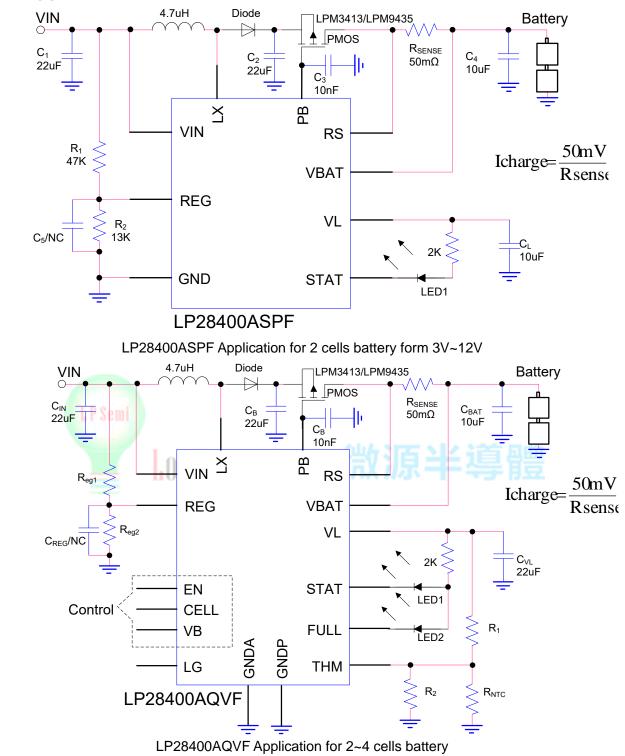
# **Pin Description**

QFN-16	ESOP8	Pin Name	I/O	Description	
1	8	РВ	0	Gate control signal for pass transistor also the compensation fo Boost.	
2	. L.	Semen	I	Enable pin, active high.	
3	1	VIN	Ι	Power input.	
4	2	VL 🚺	0	Internal LDO output. Connect a decoupling 4.7uF capacitor to GNDP.	
5		LG	0	Low side gate driver for outside power mosfet.	
6	3	LX	Р	Switching Node Connection.	
7,17	9	GNDP	Р	Ground for Power section.	
8		GNDA	Р	Ground for the analog circuits.	
9		ТНМ	I	Thermistor input. If $V_{THM}$ <0.28*V(VL) the charging is inhibited. If 0.28*V(VL) <v_{thm}<0.74*v(vl) <math="" charger="" if="" normally.="" operates="" the="">V_{THM}&gt;0.74*V(VL) the charging is inhibited.</v_{thm}<0.74*v(vl)>	
10		FULL	0	Battery full indication pin, active low.	
11	4	STAT	0	Indicates charge status. Active low when charging is on.	
12	5	REG	Ι	Input voltage feedback for the input voltage regulation loop.	
13		VB	I	Programmable battery-full voltage. Connect to GND for 8.8V,leave floating to 8.4V, and connect to VL for 8.7V	
14		CELLS	I	Cell selection. Connect to GND for 3 cells, leave floating to 2 cells, and connect to VL for 4 cells.	
15	6	RS	Ι	Indicates charging terminated.	
16	7	VBAT	Ι	Sense pin for battery voltage.	

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### **Typical Application Circuit**



NOTE: The capacitor  $C_{VL}$  must put away form LX pin.

# Absolute Maximum Ratings Note 1

$\diamond$	VIN, LX, RS, VBAT, PB to GND0.3V to 18V
$\diamond$	VL to GND
$\diamond$	REG,STAT to GND0.3V to VL+0.3V
$\diamond$	Maximum Junction Temperature 150°C
♦	Operating Junction Temperature Range (TJ)
$\diamond$	Maximum Soldering Temperature (at leads, 10 sec) 260°C
Note	e 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings
	only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the
	specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## **Thermal Information**

$\diamond$	Maximum Power Dissipation (ESOP8, P <sub>D</sub> ,T <sub>A</sub> =25°C) 2.0W	
$\diamond$	Thermal Resistance (ESOP8,J <sub>A</sub> ) 46°C/W	

## **ESD Susceptibility**

∻	HBM(Human Body Mode) Note 2 2KV
$\diamond$	MM(Machine Mode) Note 3 200V
Not	te 2. The Human body model (HBM) is a 100pF capacitor discharged through a 1.5kΩ resistor into each pin. The testing is done according
Not	te 3. Machine Model (MM) is a 200pF capacitor discharged through a 500nH inductor with no series resistor into each pin. The testing is done

Note 3. Machine Model (MM) is a 200pF capacitor discharged through a 500nH inductor with no series resistor into each pin. The test according JEDEC.

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### **Electrical Characteristics**

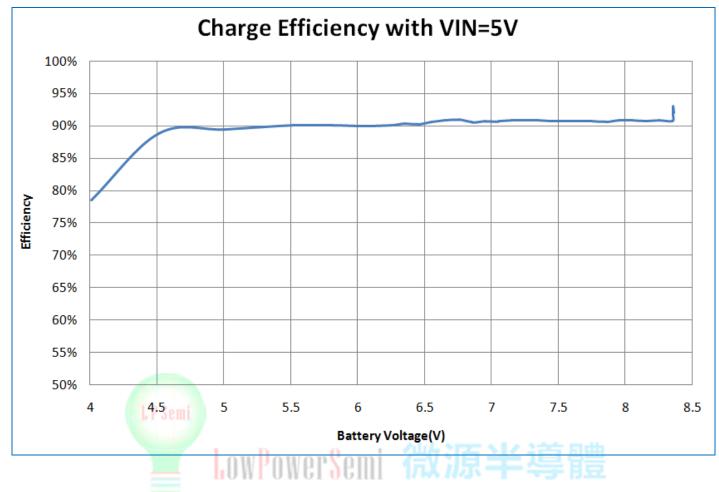
(T<sub>A</sub> = 25°C. unless otherwise noted.)

Deservator	Test Conditions	Magazinad	Limits			Units
Parameter	Test Conditions	Measured	Min	Тур	Max	Units
Quiescent current		lα		1		mA
Internal LDO output	VIN=6V	V(VL)	4.9	5	5.1	V
Input voltage regulation reference		V <sub>REG</sub>	0.95	1	1.05	V
	VBAT=8.4V, VIN=NC				-10	
Battery leakage current	VBAT=8.4V, VIN=5V	IBAT			-35	uA
Program Charging Current	From Rs to VBAT	V(RS,VBAT)	47.5	50	52.5	mV
Charge current limit	VIN=5V	IBATLIMIT		1.5		Α
CV voltage		V(VBAT)		8.4		V
Recharge threshold		V(VBAT)		300		mV
End of charge threshold	From Rs to VBAT	V(RS,VBAT)		5		mV
Trickle charge voltage threshold		V(VBAT)		6		V
Trickle charge current	From Rs to VBAT	V(RS,VBAT)		10		mV
Thermal protection	Not tested in production		135	145	155	°C
Switching frequency		LX		1		MHz
Chip enable		V <sub>EN(ON)</sub>	1.4			V
Chip shutdown		Ven(off)			0.4	V
UVLO input voltage	VIN increasing	VIN	-	2.65	-	V
UVLO Hysteresis	VIN decaying	VIN ALLA 2	H-N	150	-	mV
STAT low level	Ope <mark>n</mark> drain <mark>p</mark> ulled up with 5mA	STAT	トナ	-夺用	0.2	V
Low side Rdson	From LX to GND	R(LX,GND)		60		mΩ
THM threshold, Hot		VTHM-L		0.28*V(VL)		V
THM threshold, Cold		VTHM-H		0.74*V(VL)		V

Note: Charge current set by:  $I_{BAT} = \frac{V_{RSENSE}}{R_{SENSE}}$ 



# **Typical Operating Characteristic**



### **Function Description**

LP28400A is a wide range VIN(3V-12V), 1.5A two-cell asynchronous boost Li-Ion battery charger integrates 1MHz switching frequency and full protection functions. The charge current up to 1.5A can be programmed by using the external resistor for different portable applications and indicates the charger current information simultaneous.

It also has an adaptive input current limit for safety battery charge operation. It consists of 18V rating FETs with extremely low ON resistance to achieve high charge efficiency and simple peripheral circuit design.

#### **Battery Charge Mode**

If the plug in input voltage VIN is higher than VBAT, the switching block will stop work to keep LX pin in high resistance and PB will control the external PMOS'  $V_{GS}$  to match the battery voltage. Under this condition, the Boost charger function stops work and regulates the external FET works in linear charge mode. Whether it is work in Boost mode or Linear mode, the constant charge current is programmed by R<sub>SENSE</sub> with:

$$I_{BAT} = \frac{V_{\text{RSENSE}}}{R_{\text{SENSE}}}$$

#### Which VRSENSE=50mV

The circuit would work in trickle charge mode when battery voltage below 6V with  $V_{RSENSE}=10mV$ . The terminal charge current would be programmed by  $V_{RSENSE}=5mV$ .

During the charging mode, constant (trickle) charging current loop is active first. When VBAT equals to constant voltage threshold, constant voltage loop takes over and pull down the charging current. When  $I_{BAT}$  is lower than the termination current threshold ITERM, the main FET of boost charger is turned off firstly. External PMOS are turned off when the current is down to zero. Then, LP28400A is waiting for recharge mode.

#### Input Source Qualification

After REG amplifier powers up, the LP28400A checks the current capability of the input source. The input source has to meet the VREG>1V to enable the chip.

#### Number of Charge Cell Selection (QFN-16)

The number of charge cell can be programmed by changing the connection of CELLS Pin (QFN-16 package only). Connect CELLS Pin to GND is provide for 3 cells charging, leave floating for 2 cells and connect to VL for 4 cells.

CELLS Pin Connected	Charge Cells
Floating(No connected)	2
GND	3
VL	4

### **Preliminary**

**Datasheet** 

#### **Battery Temperature Detection**

The LP28400A continuously monitors temperature by measuring the voltage between the THM and GND pins. A negative or a positive temperature coefficient thermistor (NTC, PTC) and an external voltage divider typically develop this voltage. The LP28400A compares this voltage against its internal VTHM-L and VTHM-H thresholds to determine if charging is allowed. The temperature sensing circuit is immune to any fluctuation in VvL, since both the external voltage divider and the internal thresholds (VTHM-L)and VTHM-H) are referenced to VvL.

The resistor values of R1 and R2 are calculated by the following equations:

#### For NTC Thermistors

$$R_{1} = \frac{R\pi R\pi (K_{2} - K_{1})}{(R\pi - R\pi )K_{1}K_{2}}$$

$$R_{2} = \frac{R\pi R\pi (K_{2} - K_{1})}{R\pi (K_{1} - K_{1}K_{2}) - R\pi (K_{2} - K_{1}K_{2})}$$
For PTC Thermistors

$$R1 = \frac{R_{TL}R_{TH}(K_2 - K_1)}{(R_{TH} - R_{TL})K_1K_2}$$
$$R_2 = \frac{R_{TL}R_{TH}(K_2 - K_1)}{R_{TH}(K_1 - K_1K_2) - R_{TL}(K_2 - K_1K_2)}$$

#### K1(VTHM-L)=28% , K2(VTHM-H)=74%.

Where R(TC) is the cold temperature resistance and R(TH) is the hot temperature resistance of thermistor, as specified by the thermistor manufacturer. R1 or R2 can be omitted if only one temperature (hot or cold) setting is required. Applying a voltage between the VTHM-L and VTHM-H thresholds to pin THM disables the temperature-sensing feature.

#### **Charge state indication**

As showed below, the LED STAT respond to this five STATES.

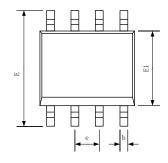
STATE	STAT Pin	LED STAT	
Without Battery	Flicker	Flicker	
Charging	Low	Light On	
Charge complete	High	Light Off	
Vreg < Vreg(th)	Low	Light On	

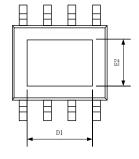


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# **Packaging Information**

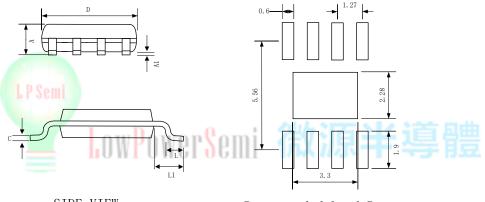
ESOP8





TOP VIEW

BOTTOM VIEW



SIDE VIEW

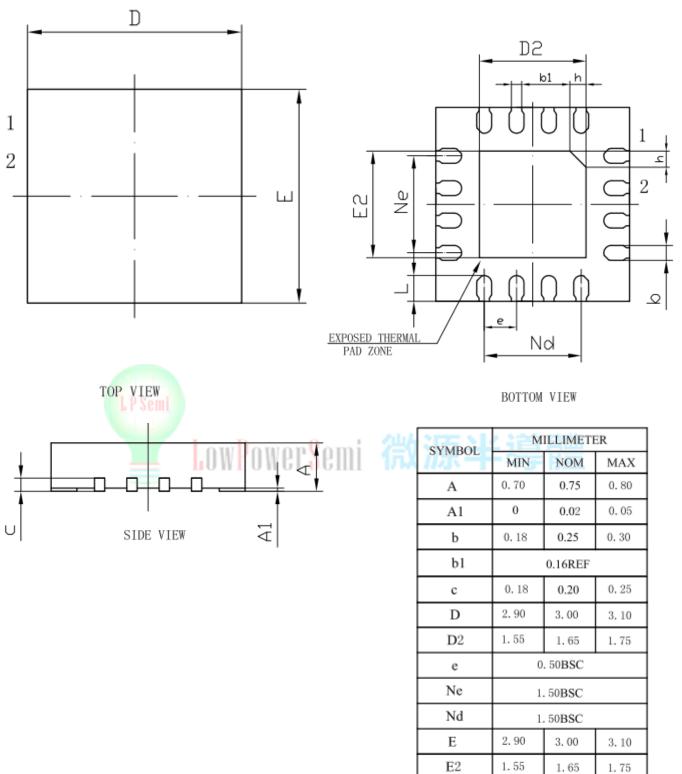
Recommended Land Pattern

	Dimensions In Millimeters				
SYMBOL	MIN	NOM	MAX		
A	1.35	-	1.75		
A1	0.00	-	0.15		
b	0.30	0.40	0.50		
С	0.20 REF				
D	4.70	4.90	5.10		
D1	3.2 REF				
E	5.70	6.00	6.30		
E1	3.70	3.90	4.10		
E2	2.30 REF				
e	1.27 BSC				
L	0.40 0.60 0.80				
L1	1.05 REF				



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L

h

0.35

0.20

0.40

0.25

0.45

0.30